

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

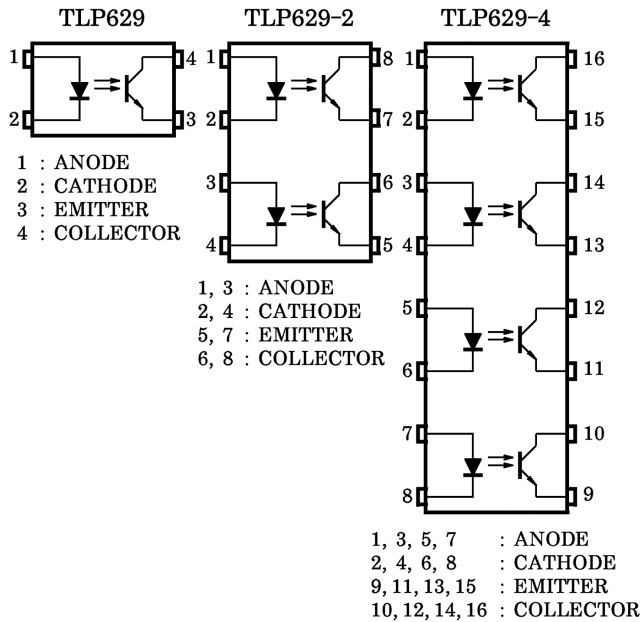
TLP629, TLP629-2, TLP629-4

Telecommunication
Office Machine
Telephone Use Equipment

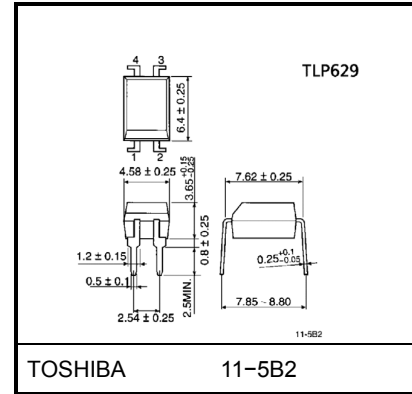
The TOSHIBA TLP629, -2, and -4 consists of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode. The TLP629-2 offers two isolated channels in an eight lead plastic DIP, while the TLP629-4 provides four isolated channels in a sixteen plastic DIP. This is suitable for application of DC input current up to 150mA.

- I_F maximum rating: 150mA
- Collector-emitter voltage: 55V (min.)
- Current transfer ratio: 25% (min.) (I_F=20mA)
- Isolation voltage: 5000V_{rms} (min.)
- UL recognized: UL1577, file no. E67349
- BSI approved: BS EN60065:2002, certificate no.7426
BS EN60950-1:2002, certificate no.7427

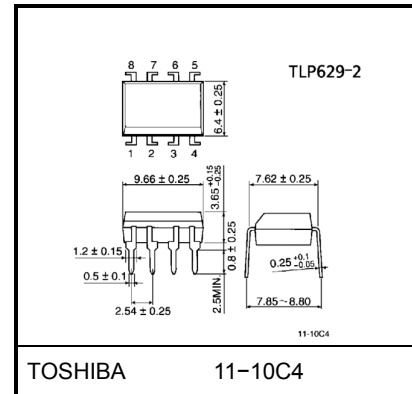
Pin Configurations (top view)



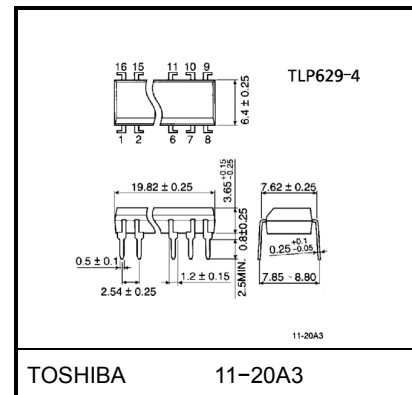
Unit in mm



Weight: 0.26 g



Weight: 0.54 g



Weight: 1.1 g

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating		Unit
			TLP629	TLP629-2,4	
LED	Forward current	I_F	150		mA
	Forward current derating	$\Delta I_F / ^\circ\text{C}$	-1.5 (Ta ≥ 25°C)		mA / °C
	Pulse forward current	I_{FP}	1 (100µs pulse, 100pps)		A
	Reverse voltage	V_R	5		V
	Junction temperature	T_j	125		°C
Detector	Collector-emitter voltage	V_{CEO}	55		V
	Emitter-collector voltage	V_{ECO}	7		V
	Collector current	I_C	80		mA
	Collector power dissipation (1 circuit)	P_C	150	100	mW
	Collector power dissipation derating (1 circuit, Ta ≥ 25°C)	$\Delta P_C / ^\circ\text{C}$	-1.5	-1.0	mW / °C
	Junction temperature	T_j	125		°C
	Storage temperature range	T_{stg}	-55~125		°C
Operating temperature range	T_{opr}	-55~100		°C	
Lead soldering temperature	T_{sol}	260 (10s)		°C	
Total package power dissipation	P_T	250	200	mW	
Total package power dissipation derating (Ta ≥ 25°C)	$\Delta P_T / ^\circ\text{C}$	-2.5	2.0	mW / °C	
Isolation voltage (Note 1)	BV_S	5000 (AC, 1min., RH ≤ 60%)		V_{rms}	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V_{CC}	—	5	24	V
Forward current	I_F	—	20	120	mA
Collector current	I_C	—	1	10	mA
Operating temperature	T_{opr}	-25	—	85	°C

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.

Individual Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
LED	Forward voltage	V_F	$I_F = 100 \text{ mA}$	—	1.4	1.7	V
	Forward current	I_F	$V_F = 0.7 \text{ V}$	—	2.5	20	μA
	Reverse current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance	C_T	$V = 0, f = 1 \text{ MHz}$	—	50	—	pF
Detector	Collector-emitter breakdown voltage	$V_{(BR) CEO}$	$I_C = 0.5 \text{ mA}$	55	—	—	V
	Emitter-collector breakdown voltage	$V_{(BR) ECO}$	$I_E = 0.1 \text{ mA}$	7	—	—	V
	Collector dark current	I_{CEO}	$V_{CE} = 24 \text{ V}$	—	10	100	nA
			$V_{CE} = 24 \text{ V}, T_a = 85^\circ\text{C}$	—	2	50	μA
Capacitance collector to emitter	C_{CE}	$V = 0, f = 1 \text{ MHz}$	—	10	—	pF	

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Current transfer ratio	I_C / I_F	$I_F = 20 \text{ mA}, V_{CE} = 1 \text{ V}$	25	—	—	%
	I_C / I_F (high)	$I_F = 100 \text{ mA}, V_{CE} = 1 \text{ V}$	20	—	80	
Collector-emitter saturation voltage	$V_{CE (sat)}$	$I_C = 2.4 \text{ mA}, I_F = 20 \text{ mA}$	—	—	0.4	V
		$I_C = 2.4 \text{ mA}, I_F = 100 \text{ mA}$	—	—	0.4	
Off-state collector current	$I_{C(off)}$	$V_F = 0.7 \text{ V}, V_{CEO} = 24 \text{ V}$	—	1	1.0	μA

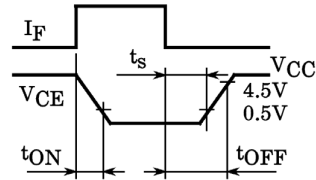
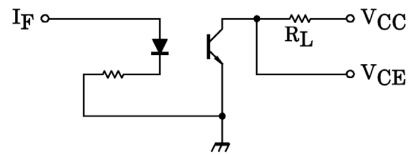
Isolation Characteristics (Ta = 25°C)

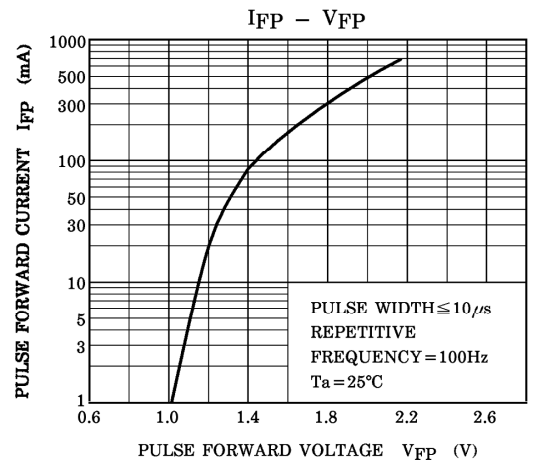
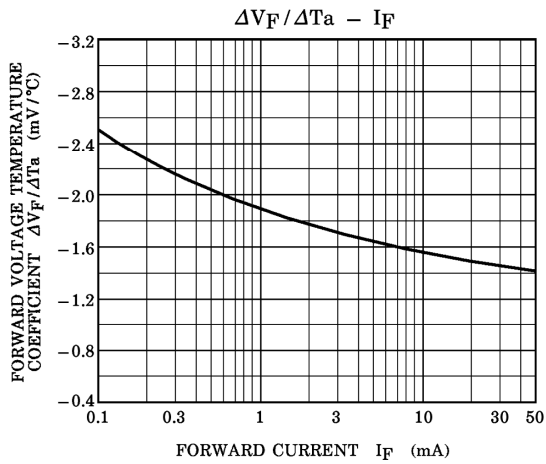
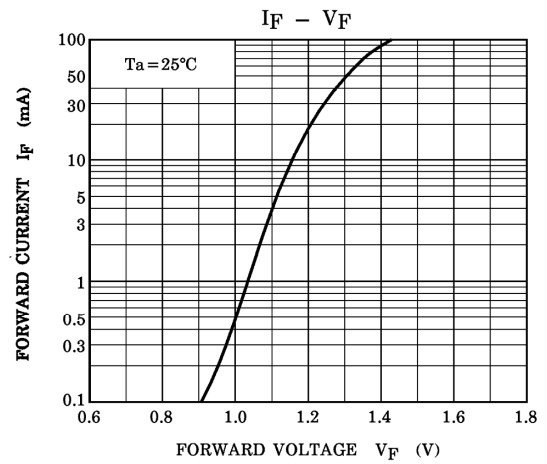
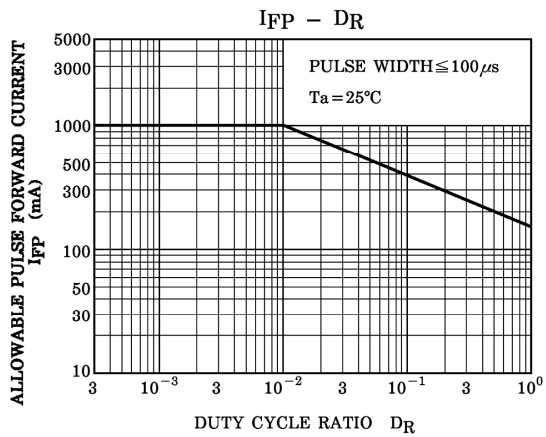
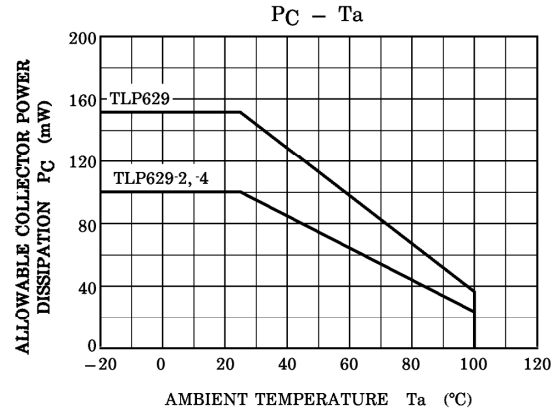
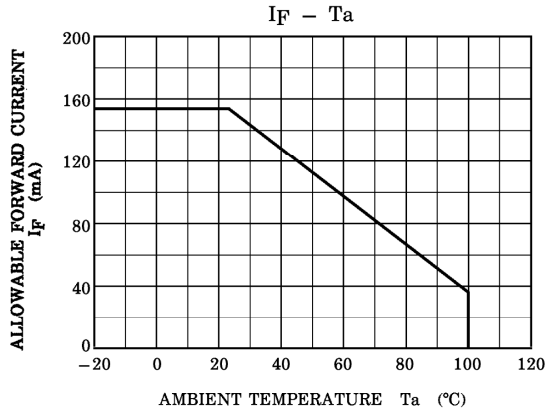
Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Capacitance input to output	C_S	$V_S = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation resistance	R_S	$V_S = 500 \text{ V}$	5×10^{10}	10^{14}	—	Ω
Isolation voltage	BV_S	AC, 1 minute	5000	—	—	V_{rms}
		AC, 1 second, in oil	—	10000	—	
		DC, 1 minute, in oil	—	10000	—	Vdc

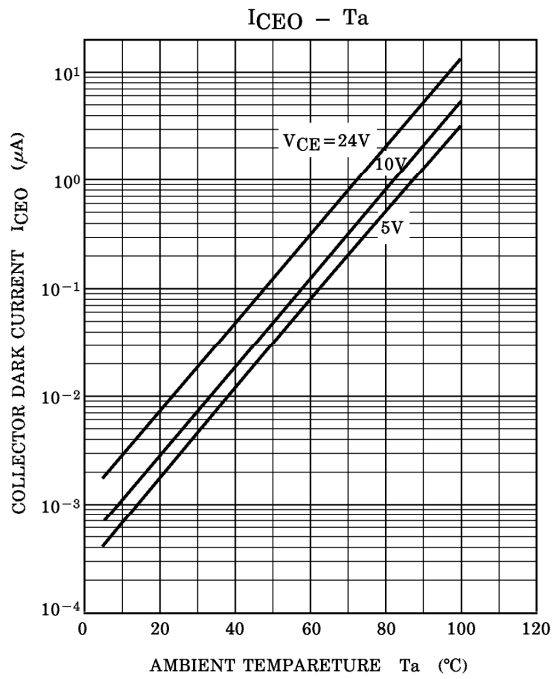
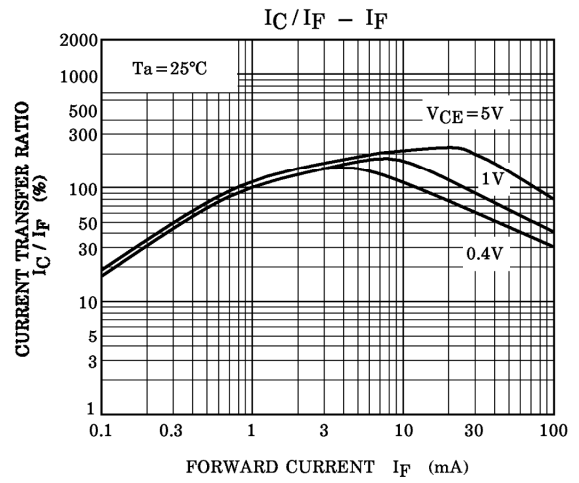
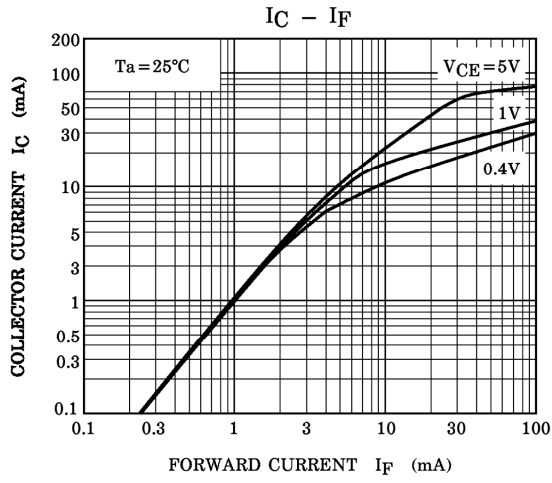
Switching Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Rise time	t_r	$V_{CC} = 10\text{ V}, I_C = 2\text{ mA}$ $R_L = 100\Omega$	—	2	—	μs
Fall time	t_f		—	3	—	
Turn-on time	t_{on}		—	3	10	
Turn-off time	t_{off}		—	3	10	
Turn-on time	t_{ON}	$R_L = 1.9\text{ k}\Omega$ $V_{CC} = 5\text{ V}, I_F = 16\text{ mA}$ (Fig.1)	—	2	—	μs
Storage time	t_s		—	15	—	
Turn-off time	t_{OFF}		—	25	—	

Fig. 1 Switching time test circuit







RESTRICTIONS ON PRODUCT USE

20070701-EN

- The information contained herein is subject to change without notice.
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